



DUAL N-CHANNEL ENHANCEMENT MODE FIELD EFFECT TRANSISTOR

Features

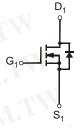
- Dual N-Channel MOSFET
- Low On-Resistance
 - 22mΩ @ V_{GS} = 10V
 - $33m\Omega$ @ $V_{GS} = 4.5V$
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Lead Free By Design/RoHS Compliant (Note 2)
- "Green" Device (Note 4)
- Qualified to AEC-Q101 Standards for High Reliability

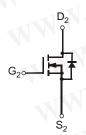
Mechanical Data

- Case: SOP-8L
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals Connections: See Diagram
- Terminals: Finish Matte Tin annealed over Copper lead frame.
 Solderable per MIL-STD-202, Method 208
- Marking Information: See Page 4
- Ordering Information: See Page 4
- Weight: 0.072grams (approximate)

SOP-8L







N-Channel MOSFET

N-Channel MOSFET

Maximum Ratings @T_A = 25°C unless otherwise specified

Chara	acteristic	10	Symbol	Value	Units
Drain-Source Voltage			V_{DSS}	30	V
Gate-Source Voltage		1 1 1 1 1 1 2	V _{GSS}	±20	V
Drain Current (Note 1)	Steady State	$T_A = 25$ °C $T_A = 70$ °C	COLID	6.9 5.8	A
Pulsed Drain Current (Note 3)			I _{DM}	30	Α

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 1)	P _D	2	W
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	62.5	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Notes:

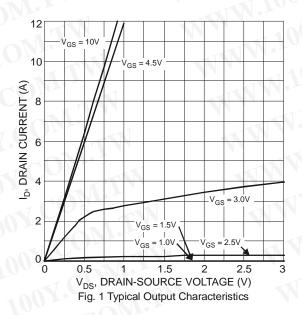
- 1. Device mounted on 2 oz. Copper pads on FR-4 PCB with $R_{\theta JA}$ = 62.5°C/W
- 2. No purposefully added lead.
- 3. Pulse width $\leq 10 \mu S$, Duty Cycle $\leq 1\%$.
- 4. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php

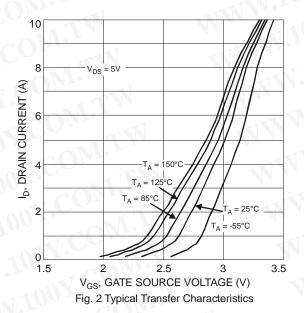


Electrical Characteristics @TA = 25°C unless otherwise specified

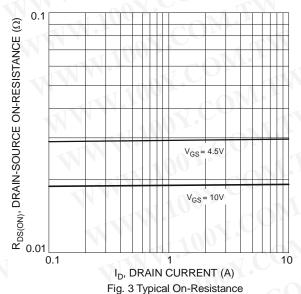
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 5)							
Drain-Source Breakdown Voltage	BV _{DSS}	30	_		V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current	I _{DSS}	1 —	_	1	μΑ	$V_{DS} = 30V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 5)	17.					COMP	
Gate Threshold Voltage	V _{GS(th)}	1	_	2.1	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
Static Drain-Source On-Resistance			_	22	~ 0	$V_{GS} = 10V, I_D = 6.9A$	
Static Dialii-Source Off-Resistance	R _{DS} (ON)	- 1	_	33	mΩ	$V_{GS} = 4.5V, I_D = 5.0A$	
Forward Transconductance	g _{fs}	UTA	7	7	S	V _{DS} =5V, I _D = 6.9A	
Diode Forward Voltage (Note 5)	V_{SD}	0.5	_	1.2	V	$V_{GS} = 0V, I_{S} = 1A$	
DYNAMIC CHARACTERISTICS	N P			41			
Input Capacitance	Ciss	# 1	725	_	pF	$V_{DS} = 15V, V_{GS} = 0V$ - f = 1.0MHz	
Output Capacitance	Coss		114	_	pF		
Reverse Transfer Capacitance	Crss		92	_	pF		
Gate Resistance	R _G	1 P 1	0.89	_	Ω	$V_{GS} = 0V, V_{DS} = 0V, f = 1.0MHz$	
SWITCHING CHARACTERISTICS		-	- 1		-31		
Total Gate Charge	Qg	M	6.4 13.0	_	nC	$V_{GS} = 4.5V$, $V_{DS} = 15V$, $I_D = 5A$ $V_{GS} = 10V$, $V_{DS} = 15V$, $I_D = 6.9A$	
Gate-Source Charge	Qgs	_	1.9	_	nC	$V_{GS} = 4.5V$, $V_{DS} = 15V$, $I_{D} = 6.9A$	
Gate-Drain Charge	Q_{gd}	7	3.2	_	nC	$V_{GS} = 4.5V, V_{DS} = 15V, I_D = 6.9A$	
Turn-On Delay Time	t _{d(on)}	()	11	_	ns	- 11	
Turn-On Rise Time	t _r	_	7	_	ns	V _{DD} = 15V, V _{GS} = 10V,	
Turn-Off Delay Time	t _{d(off)}	~ ~]	63	_	ns	$R_D = 1.8\Omega, R_G = 6\Omega$	
Turn-Off Fall Time	tf		30		ns		
	7 K K K K K		77	***	•		

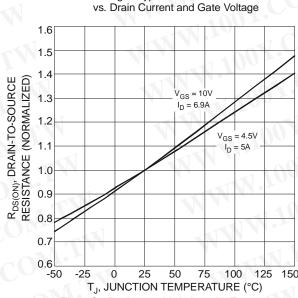
Notes: 5. Short duration pulse test used to minimize self-heating effect.

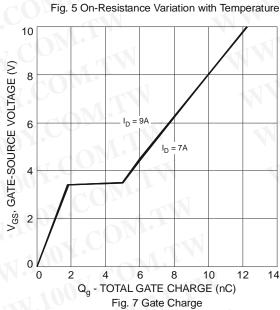












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DMN3033LSD

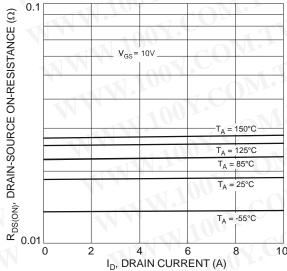
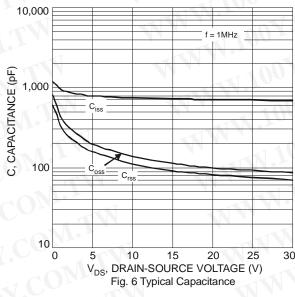


Fig. 4 Typical Drain-Source On-Resistance vs. Drain Current and Temperature



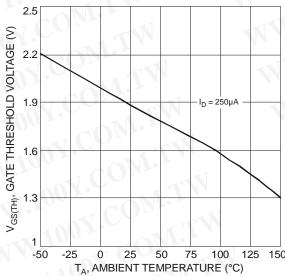
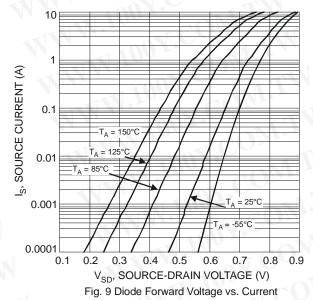


Fig. 8 Gate Threshold Variation vs. Ambient Temperature





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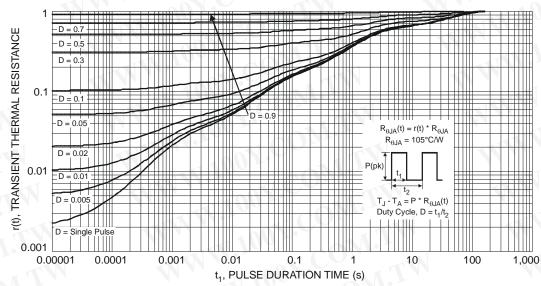


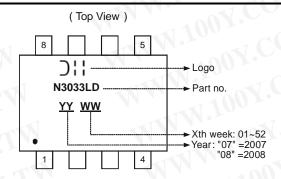
Fig. 10 Transient Thermal Response

Ordering Information (Note 6)

-			
1	Part Number	Case	Packaging
	DMN3033LSD-13	SOP-8L	2500/Tape & Reel

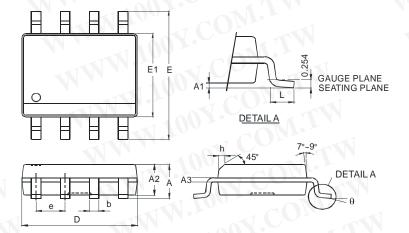
Notes: 6. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



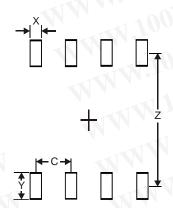


Package Outline Dimensions



SOP-8L				
Dim	Min	Max		
Α	1 1-1 -	1.75		
A1	0.08	0.25		
A2	1.30	1.50		
A3	0.20 Typ.			
b	0.3	0.5		
D	4.80	5.30		
Е	5.79	6.20		
E1	3.70	4.10		
е	1.27 Typ.			
h	- F	0.35		
L	0.38	1.27		
θ	0°	8°		
All Dimensions in mm				

Suggested Pad Layout



Dimensions	Value (in mm)
Z	5.1
C	1.27
X	0.41
Y	1.0



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